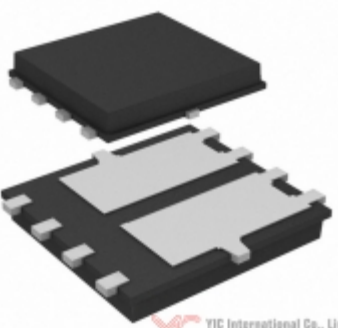

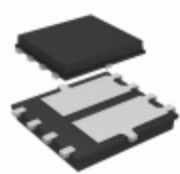
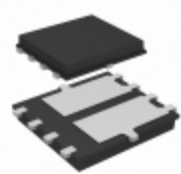

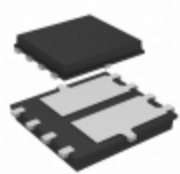


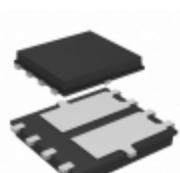
	<h2 style="color: red;">SI7911DN-T1-GE3</h2>
	Hersteller-Teilenummer: SI7911DN-T1-GE3
	Hersteller / Marke: Electro-Films (EFI) / Vishay
	Teil der Beschreibung: MOSFET 2P-CH 20V 4.2A 1212-8
	Datenblätter:  SI7911DN-T1-GE3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 55892 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	SI7911DN-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET 2P-CH 20V 4.2A 1212-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	55892 pcs Stock
detaillierte Beschreibung	Mosfet Array 2 P-Channel (Dual) 20V 4.2A 1.3W
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.3W
Verpackung / Gehäuse	PowerPAK® 1212-8 Dual
Supplier Device-Gehäuse	PowerPAK® 1212-8 Dual
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.2A
Rds On (Max) @ Id, Vgs	51 mOhm @ 5.7A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Cut Tape (CT)
Basisteilenummer	SI7911
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI7911DN-T1-GE3CT



















































SI7911DN-T1-GE3 ist neu im Original, Suche SI7911DN-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7911DN-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI7911DN-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7909DN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 12V 5.3A 1212-8</p>	 <p>SI7913DN-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 5A 1212-8</p>	 <p>SI7911DN-T1-GE3 QFN8 VISHAY SI7911DN-T1-GE3 QFN8 VISHAY</p>	 <p>SI7913DN-T1-E3 Vishay / Siliconix MOSFET 2P-CH 20V 5A 1212-8</p>
 <p>SI7911DN-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 4.2A 1212-8</p>	 <p>SI7913DN-T1-G3E VISHAY VISHAY QFN</p>	 <p>SI7911DN VISHAY SI7911DN VISHAY</p>	 <p>SI7911DN-T1-E3 Vishay / Siliconix MOSFET 2P-CH 20V 4.2A 1212-8</p>

heiße Teile

Mehr

 SI7900EDN-T1	 SI7900EDN-T1-E3	 SI7900EDN-T1-GE3	 SI7901EDN-T1	 SI7901EDN-T1-E3
 SI7901EDN-T1-E3	 SI7904BDN-T1-E3	 SI7904BDN-T1-E3	 SI7904BDN-T1-GE3	 SI7904BDN-T1-GE3
 SI7904DN	 SI7904DN-T1	 SI7904DN-T1-E3	 SI7904DN-T1-E3	 SI7904DN-T1-GE3
 SI7904DN-T1-GE3	 SI7905DN-T1-GE3	 SI7905DN-T1-GE3	 SI7909DN-T1-E3	 SI7909DN-T1-E3
 SI7909DN-T1-GE3	 SI7909DN-T1-GE3	 SI7911DN	 SI7911DN-T1-E3	 SI7911DN-T1-E3
 SI7911DN-T1-GE3	 SI7913DN-T1-E3	 SI7913DN-T1-E3	 SI7913DN-T1-GE3	 SI7913DN-T1-GE3
 SI7922DN-T1-E3	 SI7922DN-T1-E3	 SI7922DN-T1-GE3	 SI7922DN-T1-GE3	 SI7923DN-T1-E3
 SI7923DN-T1-E3	 SI7923DN-T1-GE3	 SI7923DN-T1-GE3	 SI7938DP-T1-GE3	 SI7938DP-T1-GE3
 SI7940DP	 SI7940DP-T1-E3	 SI7940DP-T1-E3	 SI7941DP-T1-E3	 SI7941DP-T1-GE3
 SI7942DP	 SI7942DP-T1-E3	 SI7942DP-T1-E3	 SI7942DP-T1-GE3	 SI7942DP-T1-GE3

Contact us: Info@Y-IC.com

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